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ON Semiconductor® FDD5614P

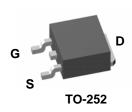
60V P-Channel PowerTrench[®] MOSFET

General Description

This 60V P-Channel MOSFET uses ON Semiconductor's high voltage PowerTrench process. It has been optimized for power management applications.

Applications

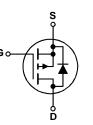
- DC/DC converter
- · Power management
- · Load switch



Features

• $-15 \text{ A}, -60 \text{ V}. \text{ R}_{DS(ON)} = 100 \text{ m}\Omega @ \text{V}_{GS} = -10 \text{ V}$ $R_{DS(ON)} = 130 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$

- · Fast switching speed
- High performance trench technology for extremely low R_{DS(ON)}
- · High power and current handling capability



Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-60	V
V _{GSS}	Gate-Source Voltage		±20	V
I _D	Drain Current – Continuous	(Note 3)	-15	A
	– Pulsed	(Note 1a)	-45	
PD	Power Dissipation for Single Operation	(Note 1)	42	W
		(Note 1a)	3.8	
		(Note 1b)	1.6	
T _J , T _{STG}	Operating and Storage Junction Temperat	ure Range	-55 to +175	°C
Therma	I Characteristics			
R _{eJC}	Thermal Resistance, Junction-to-Case	(Note 1)	3.5	°C/W
R _{θJA}	Thermal Resistance, Junction-to-Ambient	(Note 1a)	40	°C/W
R _{0JA}	Thermal Resistance, Junction-to-Ambient	(Note 1b)	96	°C/W

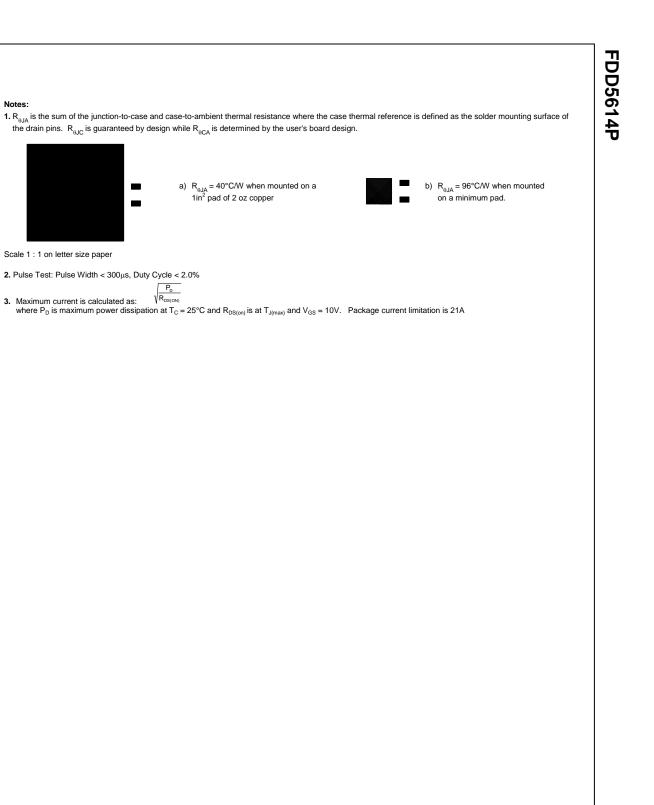
ackage Marking and Device Marking Device Deal Size Tane width

Device Marking	Device	Reel Size	Tape width	Quantity
FDD5614P	FDD5614P	13"	16mm	2500 units

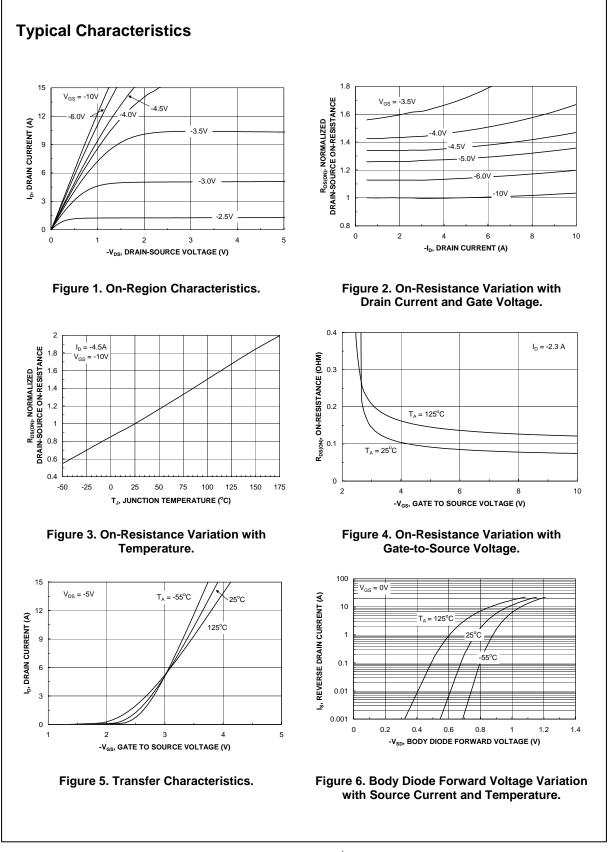
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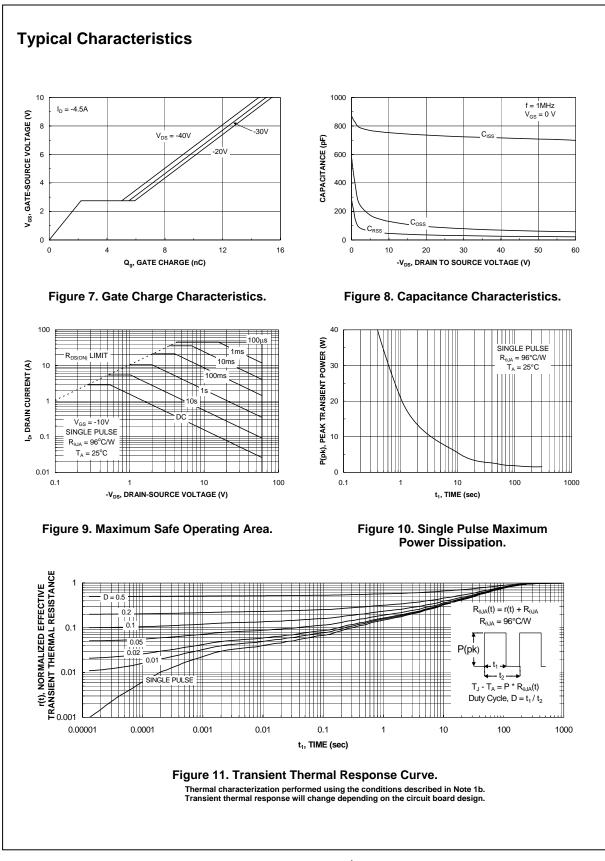
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-Sc	burce Avalanche Ratings (Note	1)				1
W _{DSS}	Single Pulse Drain-Source	$V_{DD} = -30 \text{ V}, I_D = -4.5 \text{ A}$			90	mJ
	Avalanche Energy				4.5	
AR	Maximum Drain-Source Avalanche Current				-4.5	A
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$	-60			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-49		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}} = -48 \text{ V}, V_{\text{GS}} = 0 \text{ V}$			-1	μΑ
I _{GSSF}	Gate-Body Leakage, Forward	$V_{GS} = 20V, \qquad V_{DS} = 0 V$			100	nA
I _{GSSR}	Gate-Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-1	-1.6	-3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, Referenced to 25° C		4		mV/°C
R _{DS(on)}		$V_{GS} = -10 \text{ V}, \qquad I_D = -4.5 \text{ A}$		76	100	mΩ
	On–Resistance	$V_{GS} = -4.5 \text{ V}, I_D = -3.9 \text{ A}$ $V_{GS} = -10 \text{ V}, I_D = -4.5 \text{ A}, T_J = 125^{\circ}\text{C}$		99 137	130 185	
D(on)	On–State Drain Current	$V_{GS} = -10 \text{ V}, V_{DS} = -5 \text{ V}$	-20	-	100	Α
g _{FS}	Forward Transconductance	$V_{DS} = -5 V$, $I_D = -3 A$		8		S
	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -30 V$, $V_{GS} = 0 V$,	1	759	l	pF
	Output Capacitance	f = 1.0 MHz		90		pF
C _{rss}	Reverse Transfer Capacitance	-		39		pF
	g Characteristics (Note 2)					
t _{d(on)}	Turn-On Delay Time	$V_{DD} = -30 V$, $I_D = -1 A$,	T	7	14	ns
t _r	Turn-On Rise Time	$V_{GS} = -10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		10	20	ns
t _{d(off)}	Turn-Off Delay Time			19	34	ns
t _f	Turn–Off Fall Time			12	22	ns
Q _g	Total Gate Charge	$V_{DS} = -30V, \qquad I_D = -4.5 A,$		15	24	nC
Q _{gs}	Gate–Source Charge	$V_{GS} = -10 \text{ V}$	-	2.5		nC
Q _{gd}	Gate–Drain Charge	-	-	3.0		nC
	ource Diode Characteristics	and Maximum Ratings				1
I _s	Maximum Continuous Drain–Source				-3.2	А
V _{SD}	Drain–Source Diode Forward	$V_{GS} = 0 V$, $I_S = -3.2 A$ (Note 2)		-0.8	-1.2	V
▼ SD	Voltage					



Notes:



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